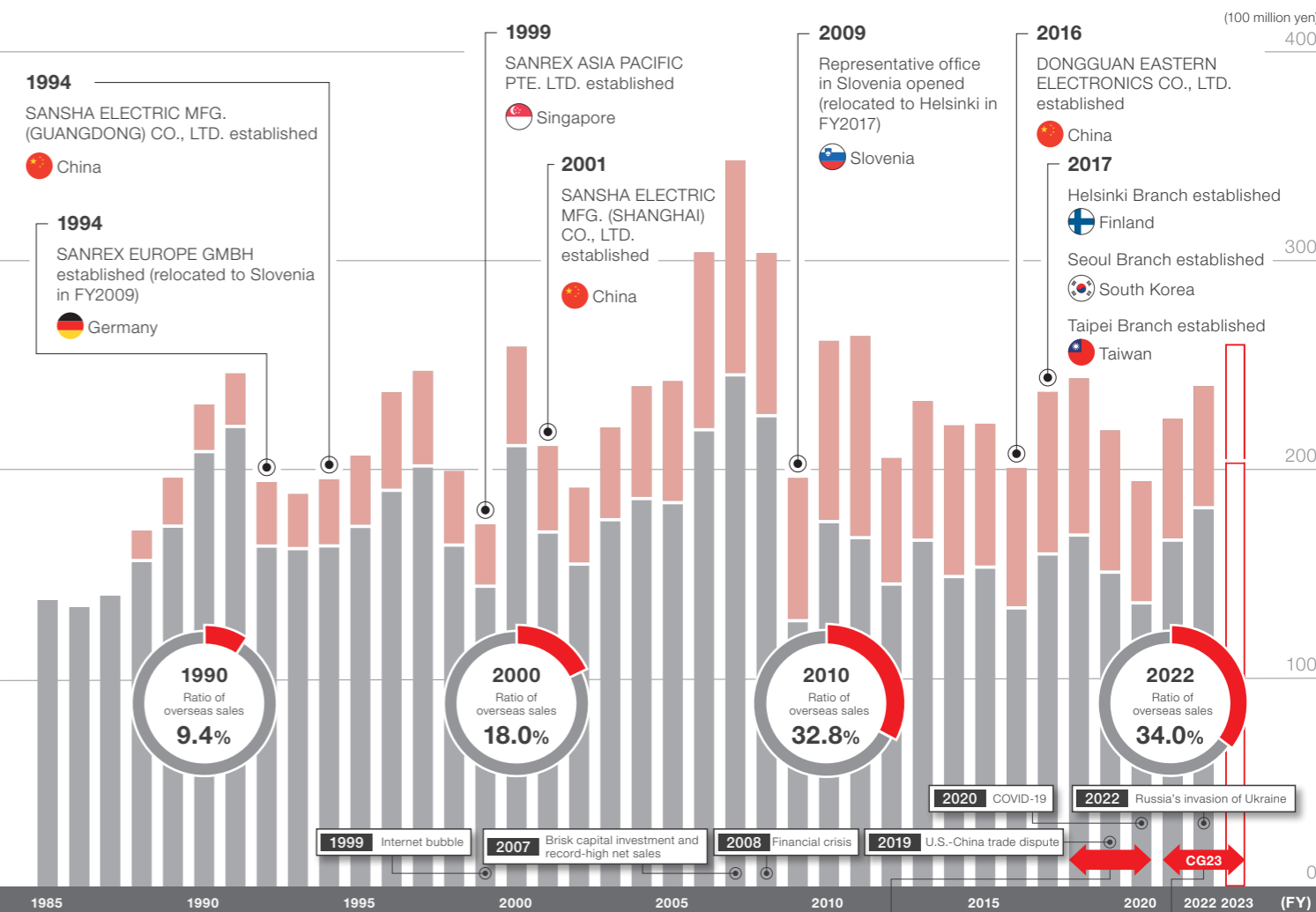
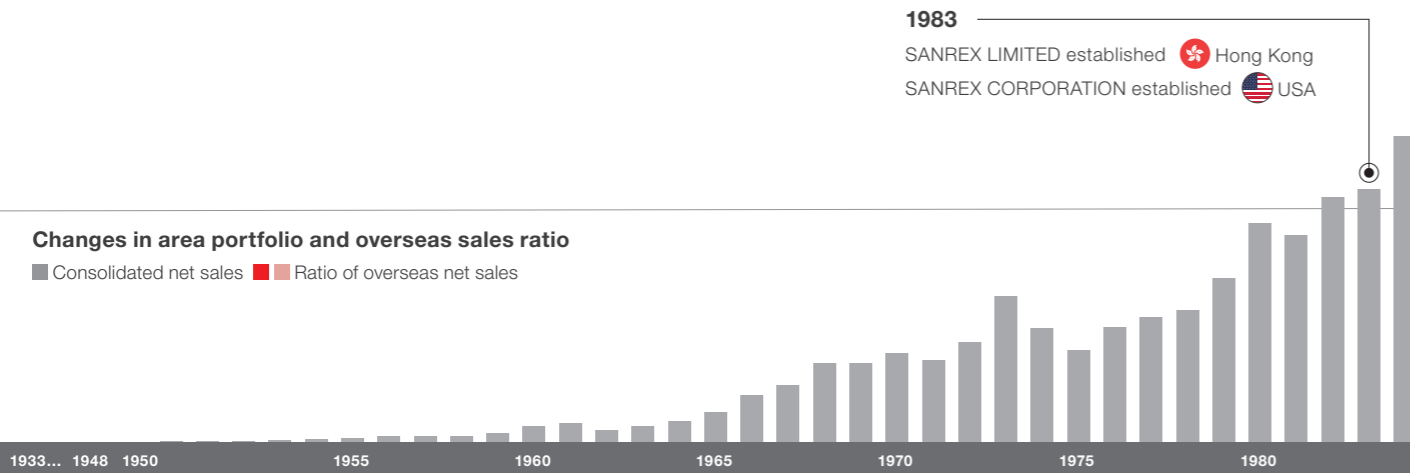


History of growth

We will continue growing by operating businesses globally

Since its founding in 1933, the Sansha Electric Manufacturing Group has been contributing to the development of society through the creation of products that society needs. Nearly four decades have passed since we launched our first overseas bases in the United States and in Hong Kong in 1983. The Group will continue to operate its business globally.



Changes in area portfolio and overseas sales ratio

■ Consolidated net sales ■ Ratio of overseas net sales

Establishing the technological foundation that continues from the foundation of the Group to the present

1933 >>> 1970

- 1933 Sansha Denki Seisakusho founded
- 1948 Sansha Denki Seisakusho Co., Ltd. established
- 1953 Tokyo District Office (currently Tokyo Branch) established
- 1960 Headquarters Plant completed in Osaka
- 1970 Fukuoka Representative Office (currently Kyushu Sales Office) established



Yukio Shikata,
founding president
Representative Director and President from the Group's foundation to 1972

Increasing bases and specialization in the development of power semiconductors

1971 >>> 1990

- 1982 Shiga Plant completed in Shiga Prefecture for the production of power supplies
- 1985 Okayama Plant completed in Okayama Prefecture for the production of power semiconductors



Masao Shikata,
second president
Representative Director and President from 1972 to 1986

Developing a system for increased globalization

1991 >>> 2010

- 1994 Shiga Plant obtains ISO 9001 certification
- 1996 Okayama Plant obtains ISO 9001 certification
- 1997 Achieves listing on the second section of the Osaka Stock Exchange
- 2001 Power Supply System Manufacturing Division obtains ISO 14001 certification
- 2002 Semiconductor Manufacturing Division obtains ISO 14001 certification



Kunio Shikata,
Honorary Chairman
Representative Director, President and Chairman of the Board from 1986 to 2021

Towards a new age

1991 >>> 2010

- 2014 New building completed at the Shiga Plant
- 2016 SANSHA SOLUTION SERVICE CO., LTD. established in Osaka
- 2016 SANSHA ELECTRIC EASTERN CO., LTD. (currently SUWA SANSHA ELECTRIC CO., LTD.) established in Nagano Prefecture to commence small power supply business
- 2021 OSAKA DENSO INDUSTRY CO., LTD. becomes a wholly owned subsidiary
- 2022 Listing moves to the Standard Market of the Tokyo Stock Exchange
- 2023 Purpose established

Product Development

- 1933 Develops a choke coil auto transformer, a predecessor to projector power supplies
- 1937 Develops a tungar rectifier for light projectors
- 1963 Develops and announces our first power semiconductor and thyristor
- 1964 Develops an inverter uninterruptible power supply and an electric power regulator for electric furnaces
- 1968 Develops a diffusion type of triac and thyristor
- 1970 Develops a rectifier for plating



Tungar rectifiers for light projectors

- 1971 Develops an insulated triac that is the first in Japan
- 1980 Develops a thyristor module and a power transistor for high speed switching
- 1982 Develops a power transistor module
- 1988 Develops a power MOSFET module



Insulated triac



Thyristor modules

- 1991 Develops a planner type transistor module
- 1993 Develops a solar power conditioner
- 2002 Develops a power supply for light source for projector of digital cinema
- 2007 Develops an IGBT chip for inverter for industrial use



Solar power conditioner



Lamp power supply for digital cinema projector

- 2014 Develops a photovoltaic power generation evaluation system for the National Institute of Advanced Industrial Science and Technology's Fukushima Renewable Energy Institute
- 2015 Jointly develops a compact SiC power module with Panasonic Corporation
- 2016 Participates in the virtual power plant (VPP) construction demonstration project
- 2017 Develops a fuel cell power conditioner
- 2019 Develops a 1500 V string compatible diode module for photovoltaic power generation
- 2020 Develops a power supply for storage battery tests
- 2022 Develops 1200 V voltage-resistant SiC MOSFET discrete semiconductor



SiC power module



1200 V voltage-resistant SiC MOSFET discrete semiconductor



Power supply for storage battery tests